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ACPL-C87AT/ACPL-C87BT

Automotive High Precision DC Voltage Isolation Sensor



Data Sheet



Description

The ACPL-C87AT/C87BT isolation sensors utilize superior optical coupling technology, with sigma-delta (Σ - Δ) analog-to-digital converter, chopper stabilized amplifiers, and a fully differential circuit topology to provide unequaled isolation-mode noise rejection, low offset, high gain accuracy and stability.

ACPL-C87AT (±1% gain tolerance) and ACPL-C87BT (±0.5% gain tolerance) are designed for high precision DC voltage sensing in electronic motor drives, DC/DC and AC/DC converter and battery monitoring system. The ACPL-C87AT/C87BT features high input impedance and operate with full span of analog input voltage up to 2.46 V. The shutdown feature provides power saving and can be controlled from external source, such as microprocessor.

The high common-mode transient immunity (15 kV/µs) of the ACPL-C87AT/C87BT maintains the precision and stability needed to accurately monitor DC rail voltage in high noise motor control environments. This galvanic safe isolation solution is delivered in a compact, surface mount stretched SO-8 (SSO-8) package that meets worldwide regulatory safety standards.

Avago R²Coupler isolation products provide the reinforced insulation and reliability needed for critical automotive and high temperature industrial applications.

Functional Diagram

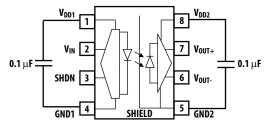


Figure 1. Functional Diagram

 $0.1\,\mu F$ bypass capacitor must be connected between pin 1 and pin 4, and pin 5 and pin 8 as shown.

Features

- Unity Gain
- +/-0.5% (ACPL-C87BT) and +/-1% (ACPL-C87AT) Gain Tolerance @ 25° C
- -0.3 mV Input Offset Voltage
- 0.05% Non Linearity
- 25 ppm/°C Gain Drift vs. Temperature
- 100 kHz Bandwidth
- 0 to 2 V Nominal Input Range
- Qualified to AEC-Q100 Grade 1 Test Guidelines
- Operating Temperature: -40° C to +125° C
- Shutdown Feature (Active High)
- 15 kV/μs Common-Mode Rejection at V_{CM} = 1 kV
- Working Voltage, V_{IORM} = 1414 V_{peak}
- Compact, Surface Mount Stretched SO8 Package
- Worldwide Safety Approval:
 - UL 1577 (5000 V_{RMS} / 1 min.)
 - CSA
 - IEC/EN/DIN EN 60747-5-5

Applications

- Automotive BMS Battery Pack Voltage Sensing
- Automotive DC/DC Converter Voltage Sensing
- Automotive Motor Inverter DC Bus Voltage Sensing
- Automotive AC/DC (Charger) DC Output Voltage Sensing
- Isolation Interface for Temperature Sensing
- General Purpose Voltage Sensing and Monitoring

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

Functional Diagram (Cont.)

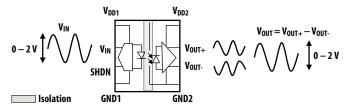


Figure 2. Functional Diagram 2

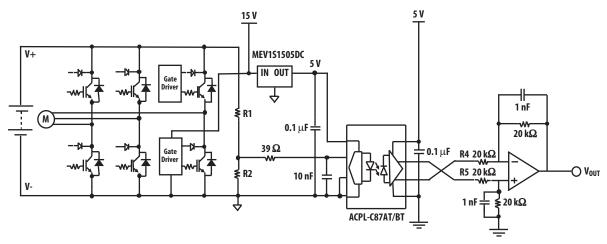


Figure 3. Typical Voltage Sensing Circuit

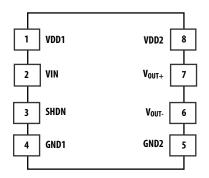


Figure 4. Package Pinout

Pin Description

Pin No.	Pin Name	Description	Pin No.	Pin Name	Description
1	V_{DD1}	Input power supply When $V_{DD1} = 0$, then $V_{OUT+} = 0$ V, $V_{OUT-} = 2.6$ V	8	V_{DD2}	Output power supply
2	V_{IN}	Voltage input, Full scale Range = 2.46 V	7	V_{OUT+}	Positive output voltage
3	SHDN	Shutdown (Active High) When active, then $V_{OUT+} = 0 \text{ V}$, $V_{OUT-} = 2.6 \text{ V}$	6	V _{OUT} -	Negative output voltage
4	GND1	Input Side Ground	5	GND2	Output Side Ground

Ordering Information

	Option	_	Surface		UL 5000 V _{rms} /	IEC/EN/DIN EN	
Part number	(RoHS Compliant)	Package	Mount	Reel	1 Minute rating	60747-5-5	Quantity
ACPL-C87AT	-000E	Stetched	Χ		Χ	Χ	80 per tube
ACPL-C87BT	-500E	SO-8	Χ	Χ	Χ	Χ	1000 per reel

To order, choose a part number from the part number column and combine with the desired option from the option column to form an order entry.

Example:

ACPL-C87AT-500E to order product of SSO-8 Surface Mount package in Tape and Reel packaging with RoHS compliant. Contact your Avago sales representative or authorized distributor for information.

Package Outline Drawing (Stretched SO8)

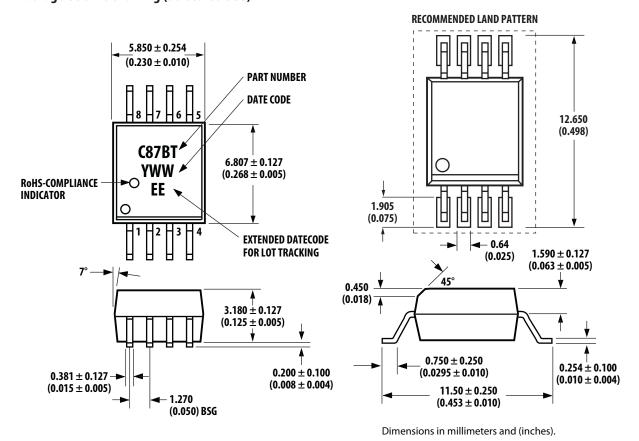


Figure 5. Package Outline Drawing

Lead coplanarity = 0.1 mm (0.004 inches). Floating lead protrusion = 0.25mm (10mils) max.

Recommended Pb-Free IR Profile

Recommended reflow condition as per JEDEC Standard, J-STD-020 (latest revision).

Note: Non-halide flux should be used

Regulatory Information

The ACPL-C87AT and ACPL-C87BT are approved by the following organizations:

UL CSA IEC/EN/DIN EN 60747-5-5

UL 1577, component recognition Approved under CSA Component IEC 60747-5-5 program up to $V_{ISO} = 5kV_{RMS}$ Acceptance Notice #5. EN 60747-5-5 DIN EN 60747-5-5

IEC/EN/DIN EN 60747-5-5 Insulation Characteristics

Description	Symbol		Units
Installation classification per DIN VDE 0110/1.89, Table 1			
for rated mains voltage ≤ 150 Vrms		I - IV	
for rated mains voltage ≤ 300 Vrms		I - IV	
for rated mains voltage ≤ 450 Vrms		I - IV	
for rated mains voltage ≤ 600 Vrms		I - IV	
for rated mains voltage ≤ 1000 Vrms		1 - 111	
Climatic Classification		40/125/21	
Pollution Degree (DIN VDE 0110/1.89)		2	
Maximum Working Insulation Voltage	V_{IORM}	1414	Vpeak
Input to Output Test Voltage, Method b	V_{PR}	2651	Vpeak
V_{IORM} X 1.875 = V_{PR} , 100% Production Test with t_m = 1 sec, Partial discharge < 5 pC			
Input to Output Test Voltage, Method a	V_{PR}	2262	Vpeak
V_{IORM} X 1.6 = V_{PR} , Type and Sample Test with $t_m = 10$ sec, Partial discharge < 5 pC			-
Highest Allowable Overvoltage	V _{IOTM}	8000	Vpeak
(Transient Overvoltage t _{ini} = 60 sec)			•
Safety-limiting values – maximum values allowed in the event of a failure,			
also see Figure 6.			
Case Temperature	Ts	175	°C
Input Current	I _{S, INPUT}	230	mA
Output Power	P _{S,OUTPUT}	600	mW
Insulation Resistance at T _S , V _{IO} = 500 V	R _S	> 10 ⁹	Ω

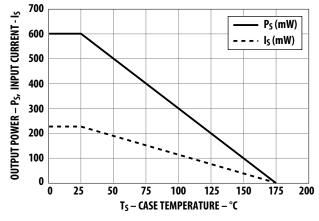


Figure 6. Dependence of safety limiting values on temperature

Insulation and Safety Related Specifications

Parameter	Symbol	Value	Unit	Conditions
Minimum External Air Gap (External Clearance)	L(101)	8.0	mm	Measured from input terminals to output terminals, shortest distance through air.
Minimum External Tracking (External Creepage)	L(102)	8.0	mm	Measured from input terminals to output terminals, shortest distance path along body.
Minimum Internal Plastic Gap (Internal Clearance)		0.5	mm	Through insulation distance conductor to conductor, usually the straight line distance thickness between the emitter and detector.
Tracking Resistance (Comparative Tracking Index)	CTI	> 175	Volts	DIN IEC 112/VDE 0303 Part 1
Isolation Group (DIN BDE0109)		Illa		Material Group (DIN VDE 0110)

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units	Note
Storage Temperature	T _S	-55	150	°C	
Ambient Operating Temperature	T _A	-40	125	°C	
Supply Voltages	V_{DD1}, V_{DD2}	-0.5	6.0	Volts	
Input Voltage	V _{IN}	-2.0	V _{DD1} + 0.5	Volts	
Shutdown Voltage	V_{SD}	-0.5	V _{DD1} + 0.5	Volts	
Output Voltages	V _{OUT+} , V _{OUT-}	-0.5	V _{DD2} + 0.5	Volts	

Recommended Operating Conditions

Parameter	Symbol	Min.	Max.	Units Notes
Ambient Operating Temperature	T _A	-40	125	°C
Input Supply Voltage	V_{DD1}	4.5	5.5	Volts
Output Supply Voltage	V_{DD2}	3.0	5.5	Volts
Input Voltage	V _{IN}	0	2.0	Volts
Shutdown Voltage	V_{SD}	V _{DD1} – 0.5	V_{DD1}	Volts

Electrical Specifications

Unless otherwise noted, all typical values at $T_A = 25$ °C, $V_{DD1} = V_{DD2} = 5$ V, $V_{IN} = 0$ to 2 V, $V_{SD} = 0$ V; all Minimum/Maximum specifications are at recommended voltage supply conditions: $4.5 \text{V} \leq V_{DD1} \leq 5.5 \text{V}$, $4.5 \text{V} \leq V_{DD2} \leq 5.5 \text{V}$

POWER SUPPLIES Input Supply Current (shutdown Mode) Ibo1 (SD) (SD) (SD) (SD) (SD) (SD) (SD) (SD)	Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Fig.	Note
Input Supply Current (Shutdown Mode)	POWER SUPPLIES								
Shutdown Mode Output Supply Current DD2 6.5 12 mA 18, 20 DC CHARACTERISTICS Gain (ACPL-C878T, +/- 0.5%) GO 0.995 1 1.005 V/V TA = 25 °C, VIN = 0 - 2 V, VDD1 = VDD2 = 5.0 V Gain (ACPL-C878T, +/- 1%) G1 0.99 1 1.01 V/V TA = 25 °C, VIN = 0 - 2 V, VDD1 = VDD2 = 5.0 V Magnitude of Gain (ACPL-C87AT, +/- 1%) G1 0.99 1 1.01 V/V TA = 25 °C, VIN = 0 - 2 V, VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs Temperature DIG/DD2 0.05 W/V TA = 25 °C 11 Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Input (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Input (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Change vs VDD1 VDD2 = 5.0 V VDD1 = VDD2 = 5.0 V Magnitude of Gain (Input Supply Current	I _{DD1}		10.5	15	mA	$V_{SD} = 0 V$	18, 19	
DC CHARACTERISTICS Gain (ACPL-C87BT, +/- 0.5%) GO 0.995 1 1.005 V/V T _A = 25 °C, V _{IN} = 0 - 2 V, V _{DD1} = V _{DD2} = 5.0 V 8 1 Gain (ACPL-C87BT, +/- 0.5%) GI 0.99 1 1.01 V/V T _A = 25 °C, V _{IN} = 0 - 2 V, V _{DD1} = V _{DD2} = 5.0 V 8, 11 1 Gain (ACPL-C87AT, +/- 1%) [dG/dTA] 25 ppm/°C T _A = -40 °C to +125 °C 11 Magnitude of Gain Change vs Temperature [dG/dV _{DD1}] 0.05 %/V T _A = 25 °C 12 Magnitude of Gain Change vs V _{DD1} [dG/dV _{DD2}] 0.02 %/V T _A = 25 °C 12 Magnitude of Gain Change vs V _{DD2} NL 0.05 0.12 %/V T _A = 25 °C 12 Nonlinearity NL 0.05 0.12 %/V T _A = 25 °C 15, 16 Input Offset Voltage Vos -10 -0.3 10 mV V _{IN} is shorted to GND1, T _A = -40 °C to +125 °C 7, 9, T _A = -40 °C to +125 °C Imput Saho Output St V Referenced to GND1 7, 9 1.2 - 40 °C to +125		I _{DD1(SD)}		20		μΑ	$V_{SD} = 5 V$		
Gain (ACPL-C87BT, +/- 0.5%) GO 0.995 1 1.005 V/V TA = 25 °C, VIN = 0 - 2 V, VDD1 = VDD2 = 5.0 V 8 1 Gain (ACPL-C87AT, +/-1%) G1 0.99 1 1.01 V/V TA = 25 °C, VDD1 = VDD2 = 5.0 V 8, 11 1 Magnitude of Gain (Change vs Temperature IdG/dVD1 25 ppm/°C TA = -40 °C to +125 °C 11 Magnitude of Gain (Change vs VDD1 IdG/dVDD1 0.05 %/V TA = 25 °C 12 Magnitude of Gain (Change vs VDD1 IdG/dVDD2 0.02 %/V TA = 25 °C 12 NL 0.05 0.12 %/V TA = 25 °C 12, 13 Input Offset Voltage VOS -10 -0.3 10 mV VIN = 0 to 2 V, TA = -40 °C to +125 °C 15, 16 Input Offset Voltage VOS -10 -0.3 10 mV VIN is shorted to GND1, TA = -40 °C to +125 °C 7, 9, TA = 25 °C 10 Magnitude of Input Offset Voltage IdV So/sdTA 21 µV°C VIN is shorted to GND1, TA = -40 °C to +125 °C 7, 9, TA = -40 °C to +125 °C 10	Output Supply Current	I _{DD2}		6.5	12	mA		18, 20	
ACPL-C87BT, +/- 0.5% Signal CAPP CA	DC CHARACTERISTICS								
ACPL-C87AT, +/- 1% VIN = 0 - 2 V, VDD1 = VDD2 = 5.0 V VDD1 VDD2 = 5.0 V VDD1 VDD2 VDD2		G0	0.995	1	1.005	V/V	$V_{IN} = 0 - 2 V,$	8	1
Change vs Temperature Magnitude of Gain Change vs V _{DD1} dG/dV _{DD1} 0.05 %/V T _A = 25 °C 12 Magnitude of Gain Change vs V _{DD2} dG/dV _{DD2} 0.02 %/V T _A = 25 °C 12, 13 Nonlinearity NL 0.05 0.12 %/V V _{IN} = 0 to 2 V, T _A = -40 °C to +125 °C 15, 16 Input Offset Voltage V _{OS} -10 -0.3 10 mV V _{IN} is shorted to GND1, T _A = -40 °C to +125 °C 7, 9, 10 Magnitude of Input Offset Change vs. Temperature dV _{OS} /dT _A 21 µV/°C V _{IN} is shorted to GND1, T _A = -40 °C to +125 °C 7, 9 INPUTS AND OUTPUTS Eull-Scale Differential Voltage Input Range FSR 2.46 V Referenced to GND1 7, 9 Input Bias Current I _{IN} -0.1 -0.001 0.1 µA V _{IN} = 0 V 22 Equivalent Input Impedance R _{IN} 1000 MΩΩ V _{IN} = 0 V, V _{SD} = 0 V 22 Output Common-Mode Voltage V _{OCM} 1.23 V V _{IN} = 0.5 V V _{IN} = 2.5 V		G1	0.99	1	1.01	V/V	$V_{IN} = 0 - 2 V$,	8, 11	1
Change vs V _{DD1} Change vs V _{DD2} IdG/dV _{DD2} 0.02 %/V T _A = 25 °C 12, 13 Nonlinearity NL 0.05 0.12 % V _{IN} = 0 to 2 V, T _A = -40 °C to +125 °C 15, 16 Input Offset Voltage V _{OS} -10 -0.3 10 mV V _{IN} is shorted to GND1, T _A = -25 °C 7, 9, 10 Magnitude of Input Offset Change vs. Temperature dV _{OS} /dT _A 21 μV/°C V _{IN} is shorted to GND1, T _A = -40 °C to +125 °C 7, 9 INPUTS AND OUTPUTS FSR 2.46 V Referenced to GND1 7, 9 Full-Scale Differential Voltage Input Range Input Bias Current I _{IN} -0.1 -0.001 0.1 μA V _{IN} = 0 V 22 Equivalent Input Impedance R _{IN} 1000 MΩΩ V _{IN} = 0 V, V _{SD} = 0 V 22 Output Common-Mode Voltage V _{OCM} 1.23 V V _{IN} = 0.5 V V _{IN} = 2.5 V	5	dG/dT _A		25		ppm/°C	$T_A = -40 ^{\circ}\text{C to} + 125 ^{\circ}\text{C}$	11	
Change vs V _{DD2} Nonlinearity NL 0.05 0.12 % V _{IN} = 0 to 2 V, T _A = -40 °C to +125 °C 15, 16 Input Offset Voltage V _{OS} -10 -0.3 10 mV V _{IN} is shorted to GND1, T _A = 25 °C 7, 9, 10 Magnitude of Input Offset Change vs. Temperature IdV _{OS} /dT _A 21 μV/°C V _{IN} is shorted to GND1, T _A = -40 °C to +125 °C 7, 9 INPUTS AND OUTPUTS FSR 2.46 V Referenced to GND1 Voltage Input Range VIN = 0 V 22 Input Bias Current I _{IN} -0.1 -0.001 0.1 μA V _{IN} = 0 V 22 Equivalent Input Impedance R _{IN} 1000 MΩ V V _{IN} = 0 V, V _{SD} = 0 V Output Common-Mode Voltage V _{OCM} 1.23 V V _{IN} = 2.5 V V _{IN} = 2.5 V		dG/dV _{DD1}		0.05		%/V	T _A = 25 °C	12	
Input Offset Voltage V_{OS} -10 -0.3 10 mV V_{IN} is shorted to GND1, 7, 9, $T_A = 25^{\circ}\text{C}$ 10 Magnitude of Input Offset Change vs. Temperature INPUTS AND OUTPUTS Full-Scale Differential Voltage Input Range Input Bias Current Input RIN -0.1 -0.001 0.1 μA $V_{IN} = 0.000$ 22 Equivalent Input Ringe RIN 1.23 $V_{IN} = 0.000$ Vin = 2.5 V	•	dG/dV _{DD2}		0.02		%/V	T _A = 25 °C	12, 13	
$T_A = 25 ^{\circ}\text{C} \qquad 10$ Magnitude of Input Offset Change vs. Temperature	Nonlinearity	NL		0.05	0.12	%		15, 16	
Offset Change vs. Temperature	Input Offset Voltage	V _{OS}	-10	-0.3	10	mV			
Full-Scale Differential Voltage Input Range	Offset Change vs.	dV _{OS} /dT _A		21		μV/°C		7, 9	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	INPUTS AND OUTPUTS								
Equivalent Input R _{IN} 1000 M Ω 22 Impedance Output Common-Mode V _{OCM} 1.23 V V _{IN} =0 V, V _{SD} = 0 V Voltage VouT+ Range V _{OUT+} Range V _{OUT+} V _{OCM} 1.23 V V _{IN} = 2.5 V		FSR		2.46		V	Referenced to GND1		
	Input Bias Current	I _{IN}	-0.1	-0.001	0.1	μΑ	$V_{IN} = 0 V$	22	
Voltage $V_{OUT+} \ Range \qquad V_{OUT+} \qquad V_{OCM} + 1.23 \qquad V \qquad V_{IN} = 2.5 \ V$		R _{IN}		1000		$M\Omega$		22	
	•	V _{OCM}		1.23		V	$V_{IN} = 0 \text{ V}, V_{SD} = 0 \text{ V}$		
V_{OUT} - Range V_{OUT} - V_{OCM} -1.23 V V_{IN} = 2.5 V	V _{OUT+} Range	V _{OUT+}		V _{OCM} +1.23		V	V _{IN} = 2.5 V		
	V _{OUT} - Range	V _{OUT-}		V _{OCM} -1.23		V	$V_{IN} = 2.5 V$		
Output Short-Circuit $ I_{OSC} $ 30 mA V_{OUT+} or V_{OUT-} , Shorted to GND2 or V_{DD2}		losc		30		mA			
Output Resistance R_{OUT} 36 Ω $V_{IN} = 0 V$	Output Resistance	R _{OUT}	·	36	·	Ω	V _{IN} = 0 V	·	

Electrical Specifications (continued)

Unless otherwise noted, all typical values at $T_A = 25$ °C, $V_{DD1} = V_{DD2} = 5$ V, $V_{IN} = 0$ to 2 V, $V_{SD} = 0$ V; all Minimum/Maximum specifications are at recommended voltage supply conditions: $4.5V \le V_{DD1} \le 5.5V$, $4.5V \le V_{DD2} \le 5.5V$

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Fig.	Note
AC CHARACTERISTICS								
Small-Signal Bandwidth (-3 dB)	f _{-3 dB}		100		kHz			
V _{OUT} Noise	N_{OUT}		1.3		mV_{RMS}	$V_{IN} = 2 V$; $BW = 1 kHz$	23	5
Input to Output Propagation Delay (10%-10%)	t _{PD10}		2.2	3.5	μs	$V_{IN} = 0$ to 2 V Step	21, 26	
Input to Output Propagation Delay (50%-50%)	t _{PD50}		3.7	6.0	μs	$V_{IN} = 0$ to 2 V Step	21, 26	
Input to Output Propagation Delay (90%-90%)	t _{PD90}		5.3	7.0	μs	V _{IN} = 0 to 2 V Step	21, 26	
Output Rise / Fall Time (10%-90%)	t _{R/F}		2.7	4.0	μs	Step Input		
Shutdown Time	t _{SD}		25		μs		25	
Shutdown Recovery Time	t _{ON}		150		μs		25	
Power Supply Rejection	PSR		-78		dB	1 Vp-p, 1 kHz sine wave ripple on V _{DD1} , differential output		
Common Mode Transient Immunity	CMTI	10	15		kV/μs	V _{CM} = 1 kV, T _A = 25 °C	24	2

Package Characteristics

Unless otherwise noted, all typical values are at $T_A = 25$ °C; all Minimum/Maximum specifications are at Recommended Operating Conditions.

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions	Fig.	Note
Input-Output Momentary Withstand Voltage *	V_{ISO}	5000			V_{RMS}	RH < 50%, $t = 1$ min., $T_A = 25$ °C		3, 4
Input-Output Resistance	R_{I-O}		10 ¹⁴		Ω	$V_{I-O} = 500 V_{DC}$		3
Input-Output Capacitance	C _{I-O}		0.5		pF	f=1 MHz		3

^{*} The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating.

Notes:

- 1. Gain is defined as the slope of the best-fit line of differential output voltage (V_{OUT+} V_{OUT-}) versus input voltage over the nominal range, with offset error adjusted. 0.5% Gain tolerance for ACPL-C87BT and 1% tolerance for ACPL-C87AT.
- 2. Common mode transient immunity (CMTI) is tested by applying a fast rising/falling voltage pulse across GND1 (pin 4) and GND2 (pin 5). The output glitch observed is less than $0.2 \, \text{V}$ from the average output voltage for less than $1 \, \mu \text{s}$.
- 3. Device considered a two terminal device: pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.
- 4. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage \geq 6000 V_{RMS} for 1 second.
- 5. Noise is measured at the output of the differential to single ended post amplifier.

Typical Characteristic Plots and Test Conditions

All $\pm 3\sigma$ plots are based on characterization test result at the point of product release. For guaranteed specification, refer to the respective Electrical Specifications section.

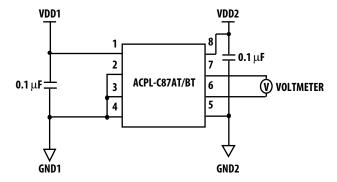


Figure 7. Input Offset Voltage Test Circuit

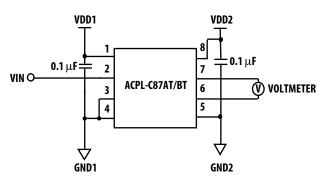


Figure 8. Gain and Nonlinearity Test Circuit

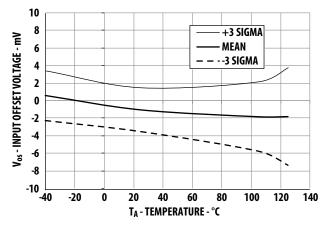


Figure 9. Input Offset Voltage vs Temperature

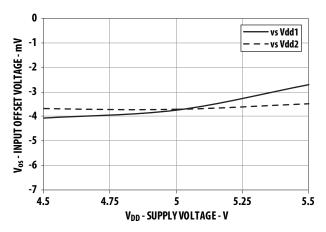


Figure 10. Input Offset vs Supply Voltage

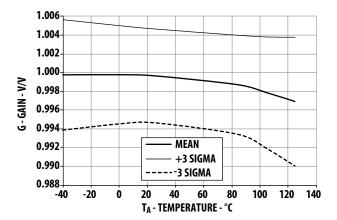


Figure 11. Gain vs Temperature

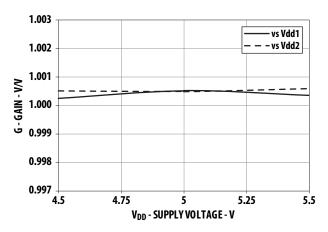


Figure 12. Gain vs Supply Voltage

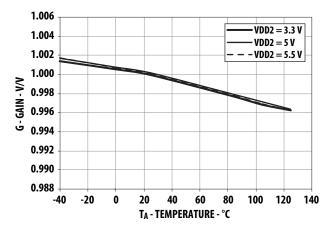


Figure 13. Gain vs Temperature at Different V_{DD2}

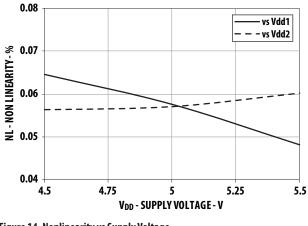


Figure 14. Nonlinearity vs Supply Voltage

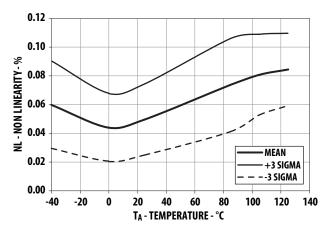


Figure 15. Nonlinearity vs Temperature

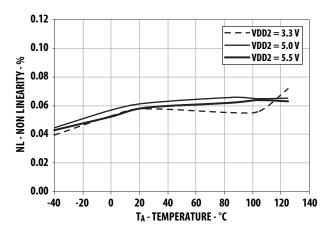


Figure 16. Nonlinearity vs Temperature at Different V_{DD2}

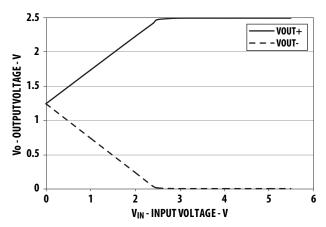


Figure 17. Output Voltage vs Input Voltage

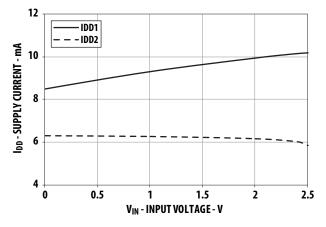


Figure 18. Typical Supply Current vs Input Voltage.

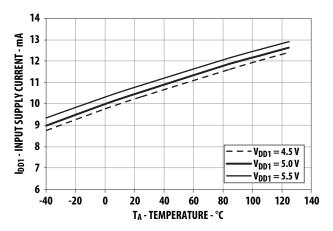


Figure 19. Typical Input Supply Current vs Temperature at Different V_{DD1}

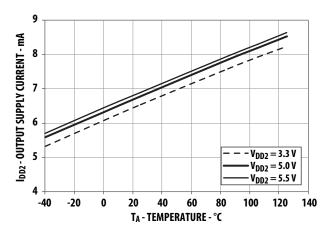


Figure 20. Typical Output Supply Current vs Temperature at Different V_{DD2}

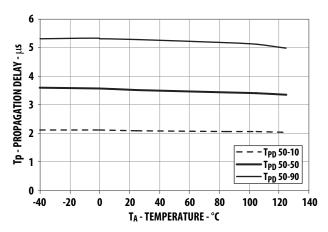


Figure 21. Typical Propagation Delay vs Temperature

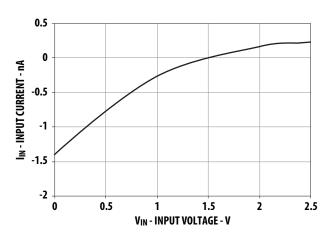


Figure 22. Input Current vs Input Voltage

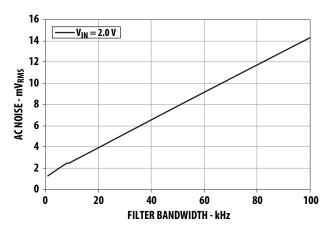


Figure 23. AC Noise vs Filter Bandwidth

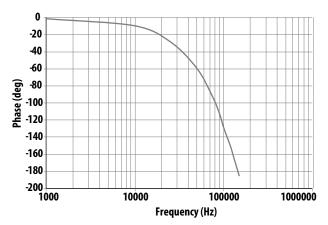


Figure 24. Phase vs Frequency

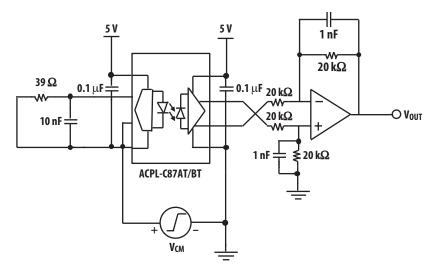


Figure 25. Common Mode Transient Immunity Test Circuit

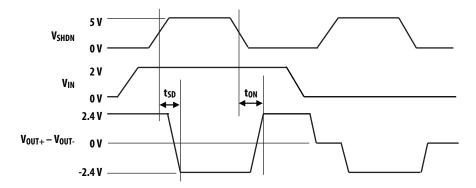


Figure 26. Shutdown Timing Diagram

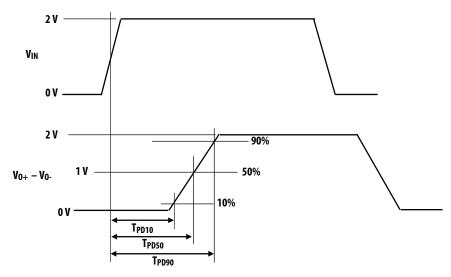


Figure 27. Propagation Delay Diagram

Application Information

The circuit shown in the Figure 28 is a high voltage sensing application using ACPL-C87AT/BT (isolation amplifier) and ACPL-M49T (optocoupler). The high voltage input is sensed by the precision voltage divider resistors R1 and sensing resistor R2. The ratio of the voltage divider is determined by the allowable input range of the isolation amplifier (0 to 2 V). This small analog input goes through a 39 Ω and 10 nF anti aliasing filter (ACPL-C87AT/BT utilize SD modulation).

Inside the isolation amplifier: the analog input signal is digitized and optically transmitted to the output side of the amplifier. The detector will then decode the signal and converted back to analog signal. The output differential signals of ACPL-C87AT/BT go through an op-amp to convert the differential signals to a single ended output.

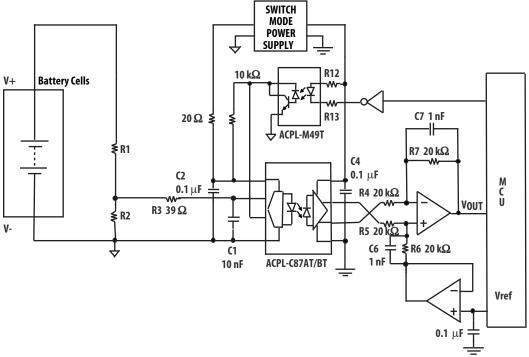


Figure 28. Typical Application Circuit for Battery Voltage Sensing

Bypass Capacitor

0.1 μF bypass capacitor must be connected as near as possible between V_{DD1} to GND1 and V_{DD2} to GND2 (Figure 29).

Anti-aliasing Filter

 $39~\Omega$ resistor and 10 nF capacitor are recommended to be connected to the input (V_{IN}) as anti-aliasing filter because ACPL-C87AT/BT uses sigma data modulation (Figure 30). The value of the capacitor must be greater than 1 nF and bandwidth must be less than 410 kHz.

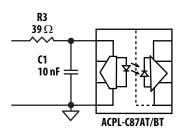


Fig 30. Anti aliasing Filter C1, R3

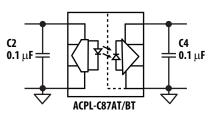


Fig 29. Bypass Capacitors C2, C4

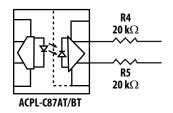


Fig 31. Loading Resistors R4, R5

Designing the input resistor divider

- 1. Choose the sensing current (Isense) for bus voltage. E.g., 1 mA
- 2. Determine R2,

$$R_2 = \frac{Voltage\ input\ range}{I_{SENSE}} = \frac{2\ V}{1\ mA} = 2\ k\Omega$$

3. Determine R1 using voltage divider formula:

$$(V+-V-) \bullet \frac{R_2}{R_1+R_2} = Voltage input range, or$$

$$R_1 = \frac{(V+-V-) \bullet R_2}{Voltage input range} - R_2$$

where (V+-V-) is the high voltage input , E.g.: 0 to 600 V,

$$R_1 = \frac{(600 \text{ V} - 0 \text{ V}) \bullet 2 \text{ k}\Omega}{2 \text{ V}} - 2 \text{ k}\Omega = 598 \text{ k}\Omega$$

To reduce the voltage stress of a sole resistor, R1 can be a series of several resistors.

Post Amplifier Circuit

The output of ACPL-C87AT/BT is a differential output (V_{OUT+} and V_{OUT-} pins). A post amplifier circuit is needed to convert the differential output to single ended output with a reference ground. The post amplifier circuit can also be configured to establish a desired gain if needed. It also functions as filter to high frequency chopper noise. The bandwidth can be adjusted by changing the feedback resistor and capacitor (R7 and C7). Adjusting this bandwidth to a minimum level helps minimize the output noise.

Post op-amp resistive loading (R4, R5) should be equal or greater than 20 k Ω (Figure 31). Resistor values lower than this can affect the overall system error due to output impedance of isolation amplifier.

The application circuit in Figure 28 features two op-amps to improve the linearity at voltage near 0 V caused by the limited headroom of the amplifier. The second op-amp can set the reference voltage to above 0 V.

Shutdown Function

ACPL-C87AT/BT has a shutdown function to disable the device and make the output (V_{OUT+} - V_{OUT-}) low. A voltage of 5V on SHDN pin will shutdown the device producing an output (V_{OUT+} - V_{OUT-}) of -2.6 V. To be able to control the SHDN function (example, from microprocessor), an optocoupler (ACPL-M49T) is used.

Total System Error

Total system error is the sum of the resistor divider error, isolation amplifier error and post amplifier error. The resistor divider error is due to the accuracy of the resistors used. It is recommended to use high accuracy resistor of 0.1%. Post Amplifier Error is due to the resistor matching and the voltage offset characteristic which can be found on the supplier datasheet.

Isolation Amplifier Error is shown in the table below:

Isolation Amplifier Error Calculation

			3σ distributio	n or specification *		
		Typical	ACPL-C87AT	ACPL-C87BT	-	Fig
Α	Error due to offset voltage (25 °C)	0.015%	0.5%	0.5%	Offset Voltage /Recommended input voltage range (2.0 V)	specs
В	Error due to offset voltage drift (across temperature)	0.1%	0.4%	0.4%	Offset Voltage /Recommended input voltage range (2.0 V)	
C	Error due to gain tolerance (25 °C)	0%	1%	0.5%		specs
D	Error due to gain drift (across temperature)	0.25%	0.8%	0.8%		
Ε	Error due to Nonlinearity (across temperature)	0.05%	0.12%	0.12%		
F	Total uncalibrated error (A+B+C+D+E)	0.415%	2.82%	2.32%		specs
G	Total offset calibrated error (F – A)	0.4%	2.32%	1.82%		
Н	Total gain and offset calibrated error (G – C)	0.4%	1.32%	1.32%		

^{*} 3σ distribution is based on corner wafers.

PCB Layout Recommendations

Bypass capacitor C2 and C4 must be located close to ACPL-C87xT Pins 1 and Pin 8 respectively. Grounded pins of C4 and C5 can be connected by vias through the respective ground layers. If the design has multiple layers, a dedicated layer for ground is recommended for flexibility in component placement.

Anti aliasing filters R3 and C1 also need to be connected as close as possible to Pin 2 of ACPL-C87AT/BT. See Figure 32 for actual component placement of the anti-aliasing filter and bypass capacitors.

GND1 and GND2 must be totally isolated in the PCB layout (Figure 33). Distance of separation depends on the high voltage level of the equipment. The higher the voltage level the larger the distance of separation needed. Designers can refer to specific IEC standard of their equipment for the creepage/clearance requirements.

R1 which is directly connected to the high voltage input must have sufficient clearance with the low voltage components. Clearance depends on the high voltage level of the input. Designers can refer to specific IEC standards of their equipment for the clearance requirements.

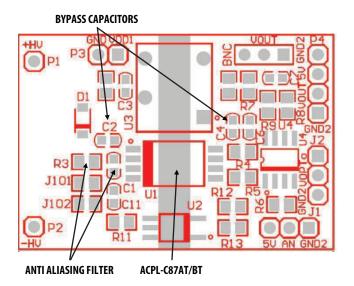


Figure 32. Component Placement Recommendation

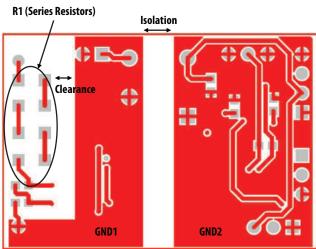


Figure 33. Bottom Layer Layout Recommendation